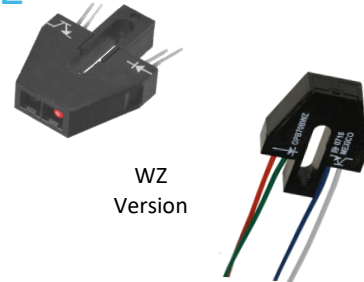


Reflective Object Sensor

OPB703 through OPB705,
 OPB703WZ through OPB705WZ,
 OPB70AWZ, OPB70DWZ, OPB70EWZ, OPB70FWZ

Obsolete (OPB70BWZ, OPB70CWZ, OPB70HWZ, OPB704G)



Features:

- Phototransistor output
- High sensitivity
- Low-cost plastic housing
- Available with lenses for dust protection and ambient light filtration
- Focused for maximum sensitivity

Description:

The **OPB703**, **OPB704** and **OPB705** consist of an Infrared (890 nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for PCBoard mounting. The **OPB703WZ**, **OPB704WZ** and **OPB705WZ** are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0 cm) minimum length, stripped and tinned.

The **OPB70AWZ** consists of an Infrared (890 nm) Light Emitting Diode (LED) and a NPN silicon Photodarlington, mounted side-by-side on converging optical axes in a black plastic housing and is designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0 cm) minimum length, stripped and tinned.

The **OPB70DWZ through OPB70FWZ** consist of a Visible (Red 660 nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor or Rbe Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0 cm) minimum length, stripped and tinned.

Various lens options are available: No lens for the (**OPB703**, **OPB703WZ**), blue window for dust protection for the (**OPB704**, **OPB704WZ**) and aperture lens for improved resolution for the (**OPB705**, **OPB705WZ**, **OPB70AWZ**, **OPB70DWZ**). The **OPB704GWZ** offers excellent protection for dirty environments.

The phototransistor responds to illumination from the emitter when a reflective object passes within the field of view centered typically at 0.15" (3.8 mm).

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor
- Mark Detection
- Office Equipment
- Gaming Equipment

Ordering Information					
Part	LED Peak	Detector	Optical Cover	Lead or Wire	
OPB703	890 nm	Transistor	None	0.160" Leads	
OPB703WZ				24" / 26 AWG Wire	
OPB704			Blue Window	0.160" Leads	
OPB704WZ				24" / 26 AWG Wire	
OPB70HWZ (Obsolete)				24" / 26 AWG Wire	
OPB704G (Obsolete)				0.160" Leads	
OPB704GWZ			24" / 26 AWG Wire		
OPB705			Darlington	Aperture	0.160" Leads
OPB705WZ					Blue Window
OPB70AWZ				Rbe Transistor	
OPB70BWZ (Obsolete)	Aperture				
OPB70CWZ (Obsolete)		Rbe Transistor			
OPB70DWZ				Transistor	
OPB70EWZ		Rbe Transistor			
OPB70FWZ	Transistor	Clear Window			



RoHS

General Note

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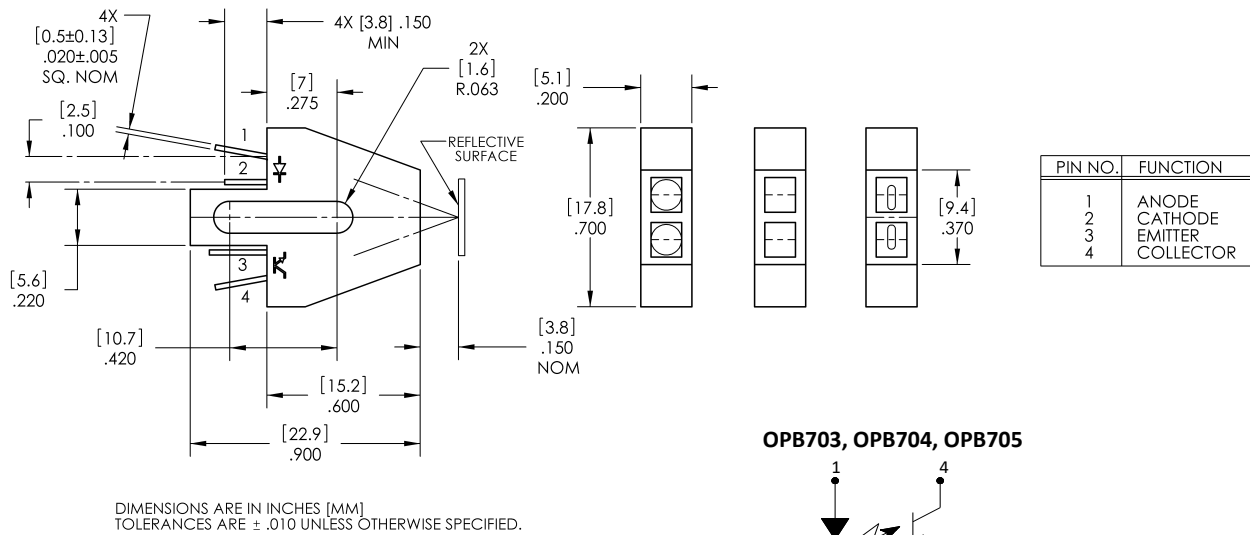
Reflective Object Sensor

OPB703 through OPB705,
 OPB703WZ through OPB705WZ,
 OPB70AWZ, OPB70DWZ, OPB70EWZ, OPB70FWZ

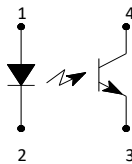


Obsolete (OPB70BWZ, OPB70CWZ, OPB70HWZ, OPB704G)

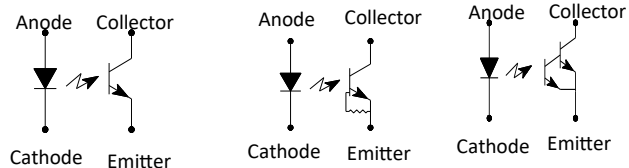
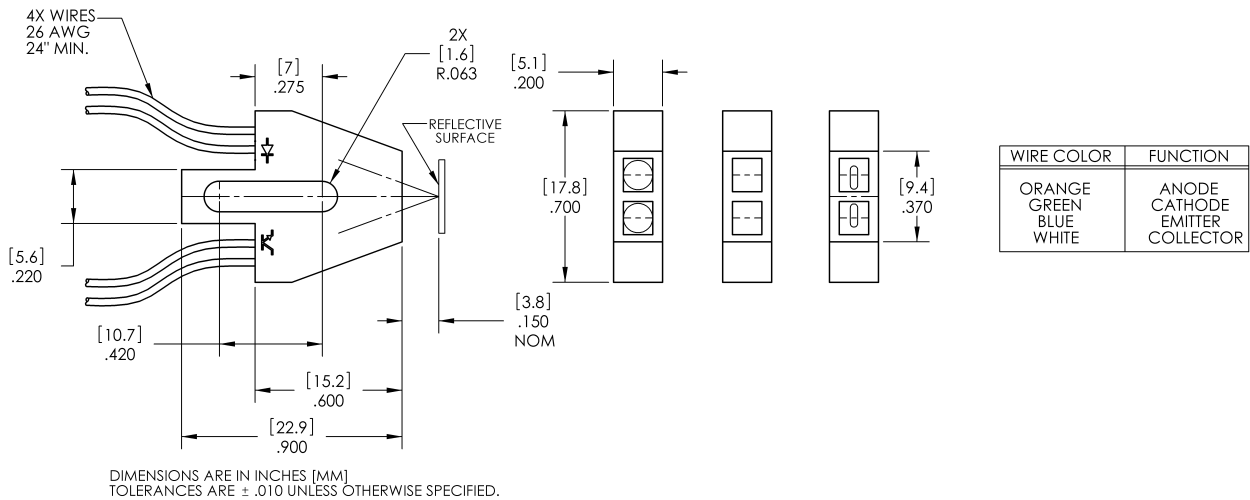
OPB703, OPB704, OPB705



OPB703, OPB704, OPB705



OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ, OPB70DWZ



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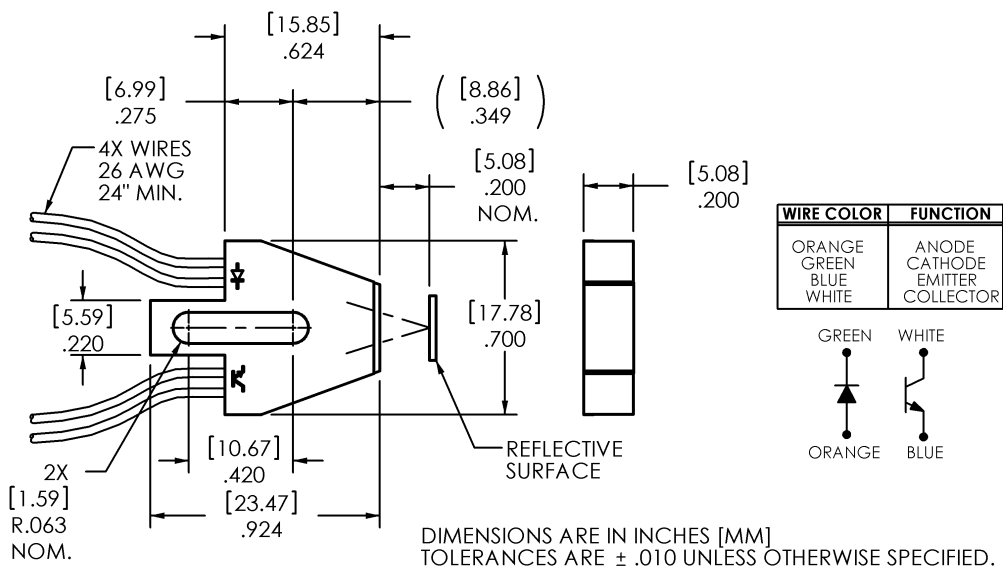
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Reflective Object Sensor

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OPB704GWZ



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Obsolete (OPB70BWZ, OPB70CWZ, OPB70HWZ, OPB704G)



Electrical Specifications

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Storage Temperature Range	-40° C to +80° C
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron]	240° C ⁽¹⁾

Input Diode

Forward DC Current	40 mA
Reverse DC Voltage	2 V
Power Dissipation	100 mW ⁽²⁾

Output Photodetector

Collector-Emitter Voltage Phototransistor	30 V
Photodarlington	15 V
Emitter-Collector Voltage	5 V
Collector DC Current	25 mA
Power Dissipation	100 mW ⁽²⁾

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703WZ, OPB704WZ, OPB705WZ and OPB704GWZ derate linearly 1.82 mW/° C above 25° C.

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Reflective Object Sensor

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OPB703WZ through OPB705WZ,
OPB70AWZ, OPB70DWZ, OPB70EWZ, OPB70FWZ

Obsolete (OPB70BWZ, OPB70CWZ, OPB70HWZ, OPB704G)



Electrical Specifications

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)
(OPB703, OPB703WZ, OPB704, OPB704WZ, OPB705, OPB705WZ, OPB704GWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage	-	-	1.7	V	$I_F = 40\text{ mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{ V}$
Output Phototransistor						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\ \mu\text{A}$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100\ \mu\text{A}$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{ V}, I_F = 0, E_E = 0$
Coupled						
$I_{C(ON)}$	On-State Collector Current OPB703, OPB703WZ OPB704, OPB704WZ OPB705, OPB705WZ	0.30 0.20 0.15	- - -	2.5 2.5 1.0	mA	$V_{CE} = 5\text{ V}, I_F = 40\text{ mA}, d = 0.15''$ ⁽⁴⁾⁽⁶⁾
	OPB704GWZ	0.50	-	6.0		$V_{CE} = 5\text{ V}, I_F = 40\text{ mA}, d = 0.20''$ ⁽⁴⁾⁽⁶⁾
I_{CX}	Crosstalk OPB703, OPB703WZ OPB704, OPB704WZ OPB705, OPB705WZ OPB704GWZ	- - - -	- - - -	20 20 10 100	μA	$V_{CE} = 5\text{ V}, I_F = 40\text{ mA}$ ⁽⁵⁾

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703, OPB704 and OPB705, derate linearly 1.67 mW/ $^\circ\text{C}$ above 25 $^\circ\text{C}$.
- (3) For OPB703WZ, OPB704WZ, OPB705WZ, OPB704GWZ, OPB70AWZ, OPB70DWZ, OPB70EWZ, and OPB70FWZ derate linearly 1.82 mW/ $^\circ\text{C}$ above 25 $^\circ\text{C}$.
- (4) The distance from the assembly face to the reflective surface is d.
- (5) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Measured using Eastman Kodak neutral white test card with 90 % diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (7) All parameters tested using pulse techniques.

General Note

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Reflective Object Sensor

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OPB703WZ through OPB705WZ,
OPB70AWZ, OPB70DWZ, OPB70EWZ, OPB70FWZ
Obsolete (OPB70BWZ, OPB70CWZ, OPB70HWZ, OPB704G)



Electrical Specifications

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)
(OPB70AWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage	-	-	1.7	V	$I_F = 40\text{ mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{ V}$
Output PhotoDarlington						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	15	-	-	V	$I_{CE} = 1.0\text{ mA}$, $E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100\ \mu\text{A}$, $E_E = 0$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{ V}$, $I_F = 0$, $E_E = 0$
Coupled						
$I_{C(ON)}$	On-State Collector Current	5.0	-	26.0	mA	$V_{CE} = 5\text{ V}$, $I_F = 40\text{ mA}$, $d = 0.15''$ ⁽¹⁾⁽³⁾
$V_{(SAT)}$	Saturation Voltage	-	-	1.15	V	$I_{CV} = 400\ \mu\text{A}$, $I_F = 40\text{ mA}$, $d = 0.15''$ ⁽¹⁾⁽³⁾
I_{CX}	Crosstalk	-	-	25	μA	$V_{CE} = 5\text{ V}$, $I_F = 40\text{ mA}$ ⁽²⁾

Notes:

- (1) The distance from the assembly face to the reflective surface is d .
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90 % diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

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Reflective Object Sensor

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OPB703WZ through OPB705WZ,
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Obsolete (OPB70BWZ, OPB70CWZ, OPB70HWZ, OPB704G)



Electrical Specifications

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)
(OPB70EWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage	-	-	2.6	V	$I_F = 40\text{ mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{ V}$
Output Phototransistor						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\ \mu\text{A}, I_F = 0, E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	0.4	-	-	V	$I_{EC} = 100\ \mu\text{A}, I_F = 0, E_E = 0$
I_{CEO}	Collector Dark Current	-	-	100	nA	$V_{CE} = 10\text{ V}, I_F = 0, E_E = 0$

Coupled

$I_{C(ON)}$	On-State Collector Current	OPB70EWZ	.25	-	2.5	mA	$V_{CE} = 5\text{ V}, I_F = 40\text{ mA}, d = 0.15''^{(1)(3)}$
$V_{(SAT)}$	Saturation Voltage		-	-	0.4	V	$I_C = 100\ \mu\text{A}, I_F = 40\text{ mA}, d = 0.15''^{(1)(3)}$
I_{CX}	Crosstalk		-	-	2	μA	$V_{CE} = 5\text{ V}, I_F = 40\text{ mA}^{(2)}$

Notes:

- (1) The distance from the assembly face to the reflective surface is d .
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90 % diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

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Reflective Object Sensor

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OPB70AWZ, OPB70DWZ, OPB70EWZ, OPB70FWZ
Obsolete (OPB70BWZ, OPB70CWZ, OPB70HWZ, OPB704G)



Electrical Specifications

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)
(OPB70DWZ and OPB70FWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage	-	-	2.6	V	$I_F = 40\text{ mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{ V}$
Output Phototransistor						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\ \mu\text{A}, I_F = 0, E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5.0	-	-	V	$I_{EC} = 100\ \mu\text{A}, I_F = 0, E_E = 0$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{ V}, I_F = 0, E_E = 0$

Coupled

$I_{C(ON)}$	On-State Collector Current	OPB70DWZ	.10	-	1.5	mA	$V_{CE} = 5\text{ V}, I_F = 40\text{ mA}, d = 0.15''^{(1)(3)}$
		OPB70FWZ	.25	-	3.5		
$V_{(SAT)}$	Saturation Voltage	-	-	0.4	V	$I_{C(ON)} = 100\ \mu\text{A}, I_F = 40\text{ mA}, d = 0.15''^{(1)(3)}$	
I_{CX}	Crosstalk	-	-	5.0	μA	$V_{CE} = 5\text{ V}, I_F = 40\text{ mA}^{(2)}$	

Notes:

- (1) The distance from the assembly face to the reflective surface is d .
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90 % diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

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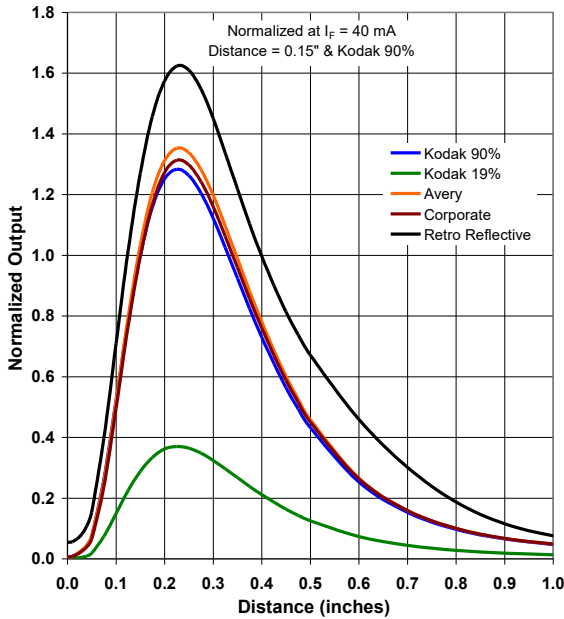
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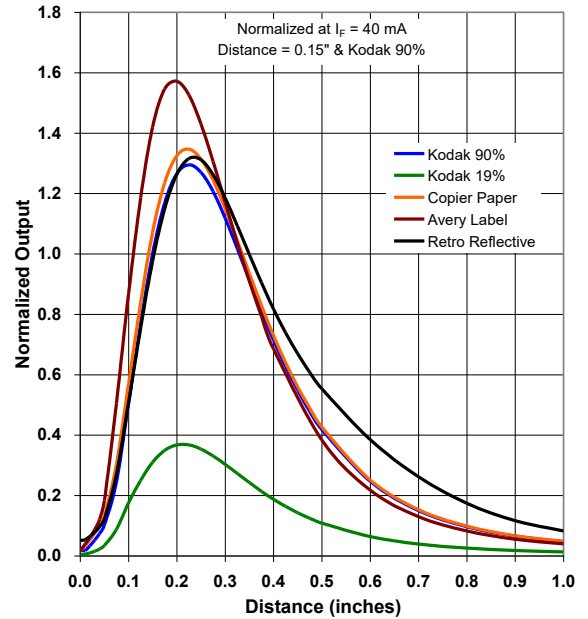


Performance

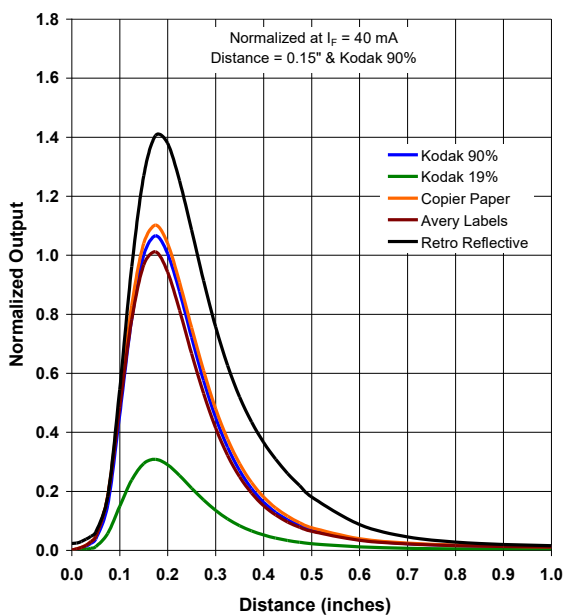
OPB703 - Output vs Distance



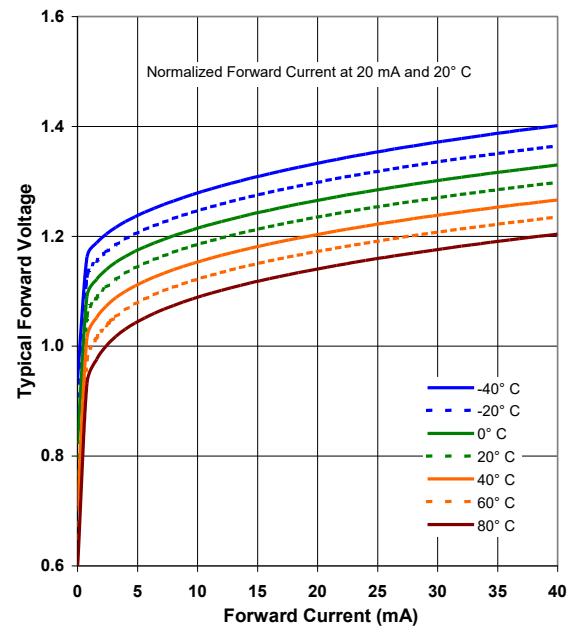
OPB704 - Output vs Distance



OPB705 - Output vs Distance



Forward Voltage vs Forward Current vs Temp



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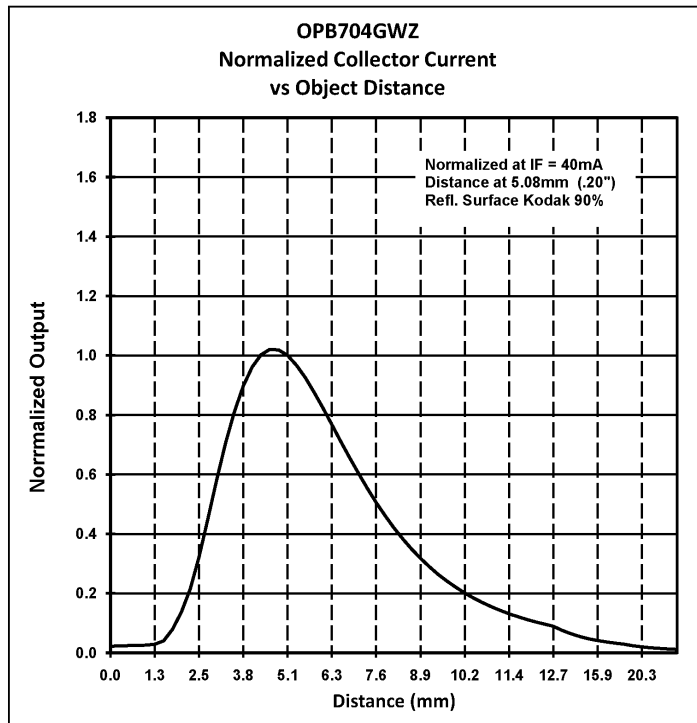
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Performance



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